

Monolithic Amplifier

LHA-23LN+

Mini-Circuits

 50Ω 30 MHz to 2 GHz

THE BIG DEAL

- Ultra-High IP3, +36.9 dBm typ
- Gain, 21.2 dB typ. at 1 GHz
- Low noise figure, 1.2 dB at 1 GHz
- Low voltage, 5V and 3V.



Generic photo used for illustration purposes only

CASE STYLE: DQ1225

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

APPLICATIONS

- Base station infrastructure
- CATV
- Cellular

PRODUCT OVERVIEW

LHA-23LN+ (RoHS compliant) is an advanced wideband amplifier fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the LHA-23LN+ has good input and output return loss over a broad frequency range. LHA-23LN+ is enclosed in a 3mm x 3mm, 12-lead MCLP package and has very good thermal performance.

KEY FEATURES

Feature	Advantages		
Broad Band: 30MHz to 2GHz	Broadband covering primary wireless communications bands: VHF, UHF, Cellular		
Extremely High IP3 40.3 dBm typical at 0.5 GHz 36.9 dBm typical at1GHz	 The LHA-23LN+ matches industry leading IP3 performance relative to device size and power consumption. The combination of the design and E-PHEMT Structure provides enhanced linearity over a broad frequency range as evidence in the IP3 being approximately 11-17 dB above the P1dB point. This feature makes this amplifier ideal for use in: Driver amplifiers for complex waveform up converter paths Drivers in linearized transmit systems Secondary amplifiers in ultra-High Dynamic range receivers 		
Low Noise Figure 1.2 dB at 1 GHz	Enables lower system noise figure performance and along with High OIP3 provides high dynamic range		
Low Supply Voltage	LHA-23LN+ supports low supply voltage operation which indicate low power consumption.		

REV. A ECO-011665 LHA-23LN+ MCL NY 220124



ULTRA HIGH DYNAMIC RANGE

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ELECTRICAL SPECIFICATIONS¹ AT 25°C, 50Ω, UNLESS NOTED OTHERWISE

Demonster	Condition	Vd=5V ¹			Vd=3V ¹	
Parameter	(MHz)	Min.	Typ.	Max.	Typ.	Units
Frequency Range		30		2000	30-2000	MHz
	30	_	23.0	_	22.3	
	500	_	21.9	_	21.1	
Gain	1000	18.9	21.2	23.1	19.9	dB
	1500	18.1	20.4	22.1	18.8	
	2000	_	19.6		17.6	
	30		12		12	
	500		11		11	
nput Return Loss	1000		10		8	dB
······································	1500		10		7	
	2000		10		8	
	30		14		16	
	500		15		18	
Dutput Return Loss	1000		19		23	dB
	1500		15		13	uD
	2000		11		9	
Reverse isolation	1000		26.9		26.6	dB
	30		22.8		17.1	dBm
	500		24.2		19.2	
Dutput Power @1 dB compression	1000		23.8		18.8	
	1500		23.2		18.4	
	2000		23.0		18.0	
	30		39.8		33.9	
	500		39.0		33.5	
Dutput IP3 ²	1000		36.9		31.6	dBm
	1500		35.2		30.7	
	2000		34.6		30.0	
	30		1.0		1.0	
	500		1.1		1.1	
Noise Figure	1000		1.2		1.2	dB
	1500		1.3		1.3	
	2000		1.5		1.6	
evice Operating Voltage			5.0		3.0	V
Device Operating Current			146	162	75	mA
Device Current Variation vs. Temperature ³			-26.1		17.5	µA/°C
Device Current Variation vs Voltage			0.0359		0.0364	mA/mV
'hermal Resistance, junction-to-ground lead unction-to-ground lead at 85°C stage temperature			23.3		23.3	°C/W

1. Measured on Mini-Circuits Characterization test board TB-1061-23LN+. See Characterization Test Circuit (Fig. 1)

2. Tested at Pout= 0 dBm / tone. 3. (Current at 105° C – Current at -45° C)/150

MAXIMUM RATINGS⁴

Parameter	Ratings
Operating Temperature (ground lead)	-40°C to 105°C
Storage Temperature	-65°C to 150°C
Power Dissipation ⁵	3.3W
Input Power (CW)	+22 dBm (5 minutes max) ⁶ +4 dBm (continuous) for 0.03-1GHz at 3V +8 dBm (continuous) for 0.03-1GHz at 5V +12 dBm (continuous) for 1-2GHz at 3V +15 dBm (continuous) for 1-2GHz at 5V
DC Voltage on Pin 7	10V

4. Permanent damage may occur if any of these limits are exceeded. Electrical maximum ratings are not

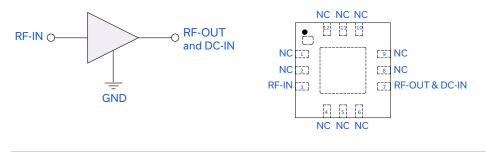
intended for continuous normal operation. 5. Up to 85°C, derate linearly to 2.5W at 105°C. 6. Up to 85°C, derate linearly to +19dBm at 105°C.



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SIMPLIFIED SCHEMATIC AND PAD DESCRIPTION



Function	Pad Number	Description
RF-IN	3	RF Input
RF-OUT and DC-IN	7	RF Output and DC Bias
GND	Paddle	Connections to ground.
NC	1-2, 4-6, 8-12	No connection, grounded externally

CHARACTERIZATION TEST / RECOMMENDED APPLICATION CIRCUIT

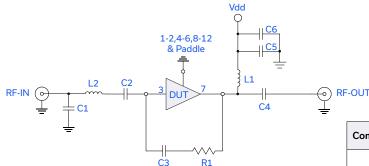


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization test board TB-1061-23LN+)

Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

1. Gain and Return loss: Pin= -25dBm

2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/ tone at output.

Components	Size	Value	Manu- facturer	P/N
C1	0402 1.2pF 0.1uF 0.001uF 0.01uF	1.2pF		GRM1555C1H1R2WA01D
C2,C3,C6		0.1uF	Murata	GRM155R71C104KA88D
C4		0.001uF	wurata	GRM1555C1H102JA01D
C5		0.01uF		GRM155R71E103KA01D
R1		1.21KOhm	КОА	RK73H1ETTP1211F
L1	0805	0.68uH	Coilcraft	0805LS-681XJLB
L2	0402	1nH	Concrart	0402CS-1N0XJLW

PRODUCT MARKING



Marking may contain other features or characters for internal lot control



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ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD. TO ACCESS CLICK HERE

Performance Data	Data Table Swept Graphs		
Case Style	DQ1225 Plastic package, exposed paddle lead finish: Matte-Tin		
Tape & Reel Standard quantities available on reel	F66 7" reels with 20, 50, 100, 200, 500, 1K, or 2K devices		
Suggested Layout for PCB Design	PL-587		
Evaluation Board	TB-1061-23HLN+		
Environmental Ratings	ENV08T9		

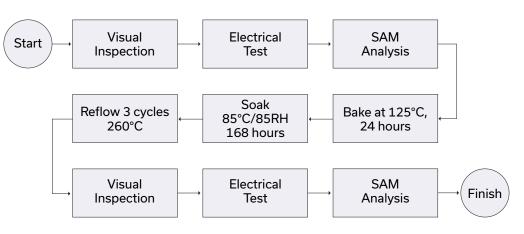
ESD RATING

Human Body Model (HBM): Class 1B (Pass 500 V) in accordance with ANSI/ESD STM 5.1 - 2001

MSL RATING

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

MSL FLOW CHART



NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard. Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp

